

# Bismuth telluride-based thermoelectric materials: Coatings as protection against thermal cycling effects

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Thermoelectric (TE) devices, both TE generators (TEGs) and TE coolers (TECs), have short service lives as TE materials undergo degradation from sublimation, oxidation and reactions in corrosive environments at high temperatures. We have investigated four high-temperature polymers (HTPs) as candidates for TE element coatings and/or TE device fillers to minimize or prevent this degradation. Two of these HTPs have shown good thermal stability in the 400–500 °C temperature range. The coatings were initially applied to bismuth telluride (Bi<sub>2</sub>Te<sub>3</sub>)-based TE materials that are used for commercial power generation devices specified for operation up to 250 °C. The HTPs protect the Bi<sub>2</sub>Te<sub>3</sub> from both weight loss and weight gain up to 500 °C. This is clearly outside the optimum TE operation range of Bi<sub>2</sub>Te<sub>3</sub> materials, but demonstrates the ability of the HTP coatings to protect the Bi<sub>2</sub>Te<sub>3</sub> materials at least up to 250 °C. The properties that HTP materials demonstrated during the examination of suitability of their use for TE element coatings and/or TE device fillers using Bi<sub>2</sub>Te<sub>3</sub> are expected to hold good for higher operating temperature TE materials also.

## I. INTRODUCTION

Solid-state thermoelectric (TE) devices are utilized in both cooling and electrical power generation applications and have several advantages over other methods, including: absence of moving parts, low maintenance, long life, and high reliability.<sup>1–3</sup> A device typically comprised two ceramics that are metalized with copper,<sup>4</sup> an array of TE elements, and a solder that joins the device together.<sup>5–7</sup> TE generator (TEG) applications have a wide range of temperature requirements with sensor energy harvesting TEGs operating around 85 °C,<sup>8</sup> standard consumer product TEGs up to about 250 °C,<sup>9</sup> automotive waste heat recovery TEGs up to about 500 °C,<sup>10</sup> and radioisotope TEGs (RTGs) operating up to about 1025 °C.<sup>11</sup> Different TE materials are required to optimize the peak TE performance at the different temperatures. For example, bismuth telluride (Bi<sub>2</sub>Te<sub>3</sub>) alloys are satisfactory up to ~250 °C, various lead telluride alloys and skutterudites satisfactory in the temperature range of 500–700 °C, and silicon germanium (SiGe) and other skutterudites up to ~1025 °C.<sup>12,13</sup> Much effort has gone into improving the bulk TE material performance for materials in

each of these temperature ranges including novel engineering of nanoscale grains and interfaces.<sup>14</sup> Our work, however, focuses on protection of the TE material at a more macro-scale, i.e., at the device assembly level.

At TEG operating temperatures, the different TE materials need protection to prevent sublimation and reaction with oxidative and corrosive environments depending on the specific application. TEGs experience preferential sublimation of the thermoelectric material. For example, in (Bi<sub>2</sub>Te<sub>3</sub>) alloys, tellurium (Te) sublimates before either bismuth (Bi) or lead (Pb) and deposits in empty spaces as a film or as Te oxide needles; similarly antimony (Sb) preferentially sublimates in the skutterudite antimonides, germanium (Ge) in SiGe, and Te in lead telluride (PbTe).<sup>15,16</sup> We note that n type Bi<sub>2</sub>Te<sub>3</sub> materials typically contain selenium (Se).

Previous studies have evaluated silicon dioxide (SiO<sub>2</sub>), metals and silica aerogel<sup>17</sup> as potential protective coatings on the TE elements. Ba<sub>0.3</sub>In<sub>0.2</sub>Ni<sub>0.05</sub>Co<sub>3.95</sub>Sb<sub>12</sub>/SiO<sub>2</sub> nanocomposite material with a nano-SiO<sub>2</sub> coating showed improved thermal stability after cycling to 450 °C.<sup>18</sup> Thin metallic coatings on RTG uncouples suppressed Sb sublimation at 687 °C from CeFe<sub>3.5</sub>Co<sub>0.5</sub>Sb<sub>12</sub> and Bi<sub>0.4</sub>Sb<sub>1.6</sub>Te<sub>3</sub> p-type segments and CoSb<sub>3</sub> and Bi<sub>2</sub>Te<sub>2.95</sub>Se<sub>0.05</sub> n-type segments.<sup>15</sup> However, none of the metals tested by El-Genk et al., tantalum (Ta), titanium (Ti), molybdenum (Mo) and

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vanadium (V), satisfied both minimal degradation of the uncouple's performance combined with ease of fabrication and long life.<sup>19</sup>

We explore high-temperature polymer (HTP) filler and/or coating materials as an alternative to aerogel, SiO<sub>2</sub>, or metal coatings to prevent TE material degradation from sublimation, oxidation, and corrosion up to a temperature range of 400–500 °C. Bi<sub>2</sub>Te<sub>3</sub> alloys are used as the initial TE material to test HTP candidates as there are immediate commercial applications in the 230–250 °C temperature range. HTPs that perform well at 400–500 °C will be transferable to PbTe, skutterudite and other relatively high-temperature TE devices, specifically automotive waste heat recovery.

Attempts have been made to lower sublimation rates but we would like to eliminate sublimation entirely. There are large temperature differences ( $\Delta T$  up to 250 °C) across the device as well as relatively high temperatures of power generation applications. Moreover, there are applications that require sealing the device from corrosive environments.

## II. EXPERIMENTAL METHODS AND MATERIALS

### A. Materials

TE material was fine-grained Bi<sub>2</sub>Te<sub>3</sub> Micro-Alloyed Material (MAM) from Marlow Industries and samples were diced to needed dimensions from 17-mm diameter wafers that had been sliced perpendicularly to the ingot growth direction, nominally the a-axis of the Bi<sub>2</sub>Te<sub>3</sub> rhombohedral crystal structure. Aluminum isopropoxide [Al(OC<sub>3</sub>H<sub>7</sub>)<sub>3</sub>] from Sigma-Aldrich was the precursor of boehmite AlOOH. The classic Yoldas process<sup>20–23</sup> was used to prepare boehmite suspensions in methanol. Hydrochloric acid and methanol from Sigma Chemicals Co. were analytically pure and used as received. Several HTPs were prepared at Laboratory of Advanced Polymers & Optimized Materials (LAPOM). HTP1 is a two-component system, with one component based on a phenyl glycidyl ether and the other on aniline. The system is transformed into a final product through etherification reaction at high temperature. HTP2 is made from a solution of polyimide precursor polyamic acid. The solution is heated to high temperatures to vaporize the solvent, accelerate the imidization reaction and make a nonsoluble, nonmelting insulating material with good heat resistance, chemical resistance and insulation properties. HTP4 is a thermoset cyanate ester resin with the glass transition temperatures  $\approx 280$  °C. The term “cyanate ester resin” is used to describe both a family of monomers and oligomers with reactive cyanate end groups (–O–C $\equiv$ N) on an aromatic ring and the cured resin networks into which the monomers are formed. This family of thermosetting monomers and oligomers contain at least two cyanate functional groups and will homopolymerize with the addition of heat and/or catalyst

into a thermosetting material (so called polycyanurate). HTP5 is a thermally stable polymer based on stiff aromatic backbones, infusible and insoluble due to its planar aromatic structure and it is processed via the solvent route.

### B. Encapsulation of Bi<sub>2</sub>Te<sub>3</sub> materials

Encapsulation was achieved by dip coating and/or by painting the free surface sides of Bi<sub>2</sub>Te<sub>3</sub> substrates. The coatings were dried and/or cured at elevated temperatures. Before electrical conduction tests, the coating on the material was carefully peeled off so as to test the thermoelectric material instead of the polymeric material.

### C. Thermogravimetric analysis

Thermogravimetric analysis (TGA) was performed on a Perkin Elmer TG-7 apparatus (Waltham, MA). Thermal analysis techniques are well described by Menard,<sup>24</sup> Lucas et al.,<sup>25</sup> by Gedde<sup>26</sup> and by Saiter et al.<sup>27</sup> 10 mg of each dried sample were heated from + 50 to + 600 °C at 10 °C/min.

### D. Environmental scanning electron microscopy and energy-dispersive spectroscopy

Energy-dispersive spectroscopy (EDS) of the samples was collected using a FEI Quanta ESEM (Hillsboro, OR) configured with EDS.

### E. Profilometry

The roughness of the samples was measured with a Veeco Dektak 150 Profilometer (Plainview, NY). The stylus tip had a radius of 12.5  $\mu\text{m}$ , the applied force was 1.0 mg and the scan rate 0.033  $\mu\text{m/s}$ .

### F. Electric resistivity

A four-point Keithley SourceMeter (Cleveland, OH) was used to measure electrical resistivity. The conductivity of Bi<sub>2</sub>Te<sub>3</sub> is anisotropic. The electrical conductivity perpendicular to the ingot growth direction (nominally the a-axis direction) is approximately four times as large as that perpendicular to the ingot growth direction (nominally the c-axis direction).<sup>1</sup> Given the sample orientation relative to crystal growth direction, the probes contact a planar surface that is parallel to the ingot growth direction (nominally c-axis direction). However, this may be of academic interest only as the change in resistivity is the parameter of interest and all samples were measured in the same orientation for both pre- and post measurements.

## III. EFFECTS OF HEATING ON COMPOSITION AND MORPHOLOGY

As TE devices are subjected to thermal cycling, we used TGA to locate temperatures of various thermal

decomposition processes and to determine the amounts of volatiles. Results for a  $\text{Bi}_2\text{Te}_3$  sample are shown in Fig. 1.

Figure 1 shows a slight mass loss (note the left scale) up to 400 °C. There is a steeper slope ( $\text{wt}\%/^\circ\text{C}$ ) in the mass loss up to  $\sim 160$  °C and this is likely due to desorption and evaporation of absorbed residues such as moisture. The mass loss slope is more gradual from  $\sim 160$  to  $\sim 400$  °C and this may be due to sublimation of tellurium. However, starting at approximately 400 °C the diagram shows relatively sharp weight gain. Apparently a chemical reaction with something from the environment takes place. If tellurium is escaping, then oxidation of bismuth is a likely candidate for that reaction. This hypothesis is tested below by other means. Given the heating rate of 10 °C/min and the sharply upward trend of the curve, the oxidation reaction has not been completed during the run.

To evaluate the sublimation and oxidation hypotheses formulated above, we have applied EDS to n-type  $\text{Bi}_2\text{Te}_3$  samples before [Fig. 2(a)] and after [Fig. 2(b)] the TGA examination.

We note 0.4 to 1.3 wt% oxygen at different sample areas of an unheated  $\text{Bi}_2\text{Te}_3$  specimen prior to TGA. This implies different levels of initial oxidation during the production or storage period possibly caused by a non-uniform distribution of defects in  $\text{Bi}_2\text{Te}_3$  crystals. Areas with large defects might provide high oxidation levels. The oxygen peak in Fig. 2(b) shows oxidation occurred

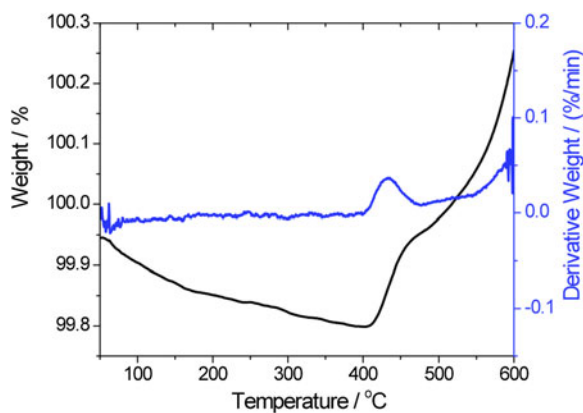


FIG. 1. TGA thermogram and its derivative for  $\text{Bi}_2\text{Te}_3$ .

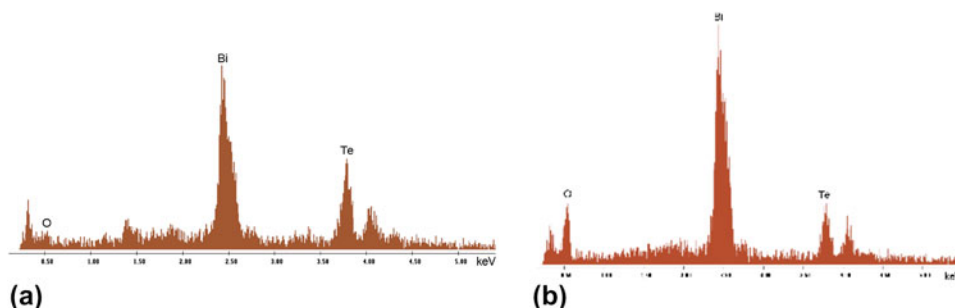


FIG. 2. EDS results: n-type  $\text{Bi}_2\text{Te}_3$  (a) and n-type  $\text{Bi}_2\text{Te}_3$  after a TGA run (b).

during the TGA run. The ratio of the Te peak to the Bi peak after the run is smaller and the small 1.4 keV Se peak in 2(a) is absent in 2(b). We recall that n-type  $\text{Bi}_2\text{Te}_3$  alloys typically contain Se. These data suggest a loss of Te and Se during heating of the  $\text{Bi}_2\text{Te}_3$ ; a plausible explanation is sublimation.

We have also studied morphology changes caused by heating using scanning electron microscopy (SEM); see Fig. 3. Samples were heated in a TGA apparatus up to 550 °C.

We see in Fig. 3 hollow microstructures caused by heating—a result of sublimation. The empty domains and degradation of the crystalline structure are more visible on the fractured surfaces, a darker color possibly a sign of oxidation. Thus, also environmental scanning electron microscopy (ESEM) images support our hypotheses on oxidation and sublimation of  $\text{Bi}_2\text{Te}_3$  components during heating.

#### IV. ELECTRICAL RESISTIVITY

We now consider effects of heating on the electrical resistivity. Both n-type and p-type  $\text{Bi}_2\text{Te}_3$  samples were left at either 250 or 500 °C for an hour. Then electrical resistivity was determined at 25 °C for each sample; see the results in Fig. 4. The current versus voltage diagrams are also included in that figure.

As expected, the resistivity values decrease with higher heating temperature in all cases. Compared with initial specimens, the resistivity values of both types of  $\text{Bi}_2\text{Te}_3$  samples are slightly higher after 1 h of heating at 250 °C temperature and much higher after heating to 500 °C. These results are also in agreement with our model of sublimation and oxidation. We have seen above manifestations of these processes in TGA, EDS and ESEM. Clearly metal sublimation and/or oxidation at high temperatures increase electric resistivity.

#### V. ENCAPSULATED MATERIALS

The key question is how to extend the service life of TE devices. Our approach is based on using a coating to

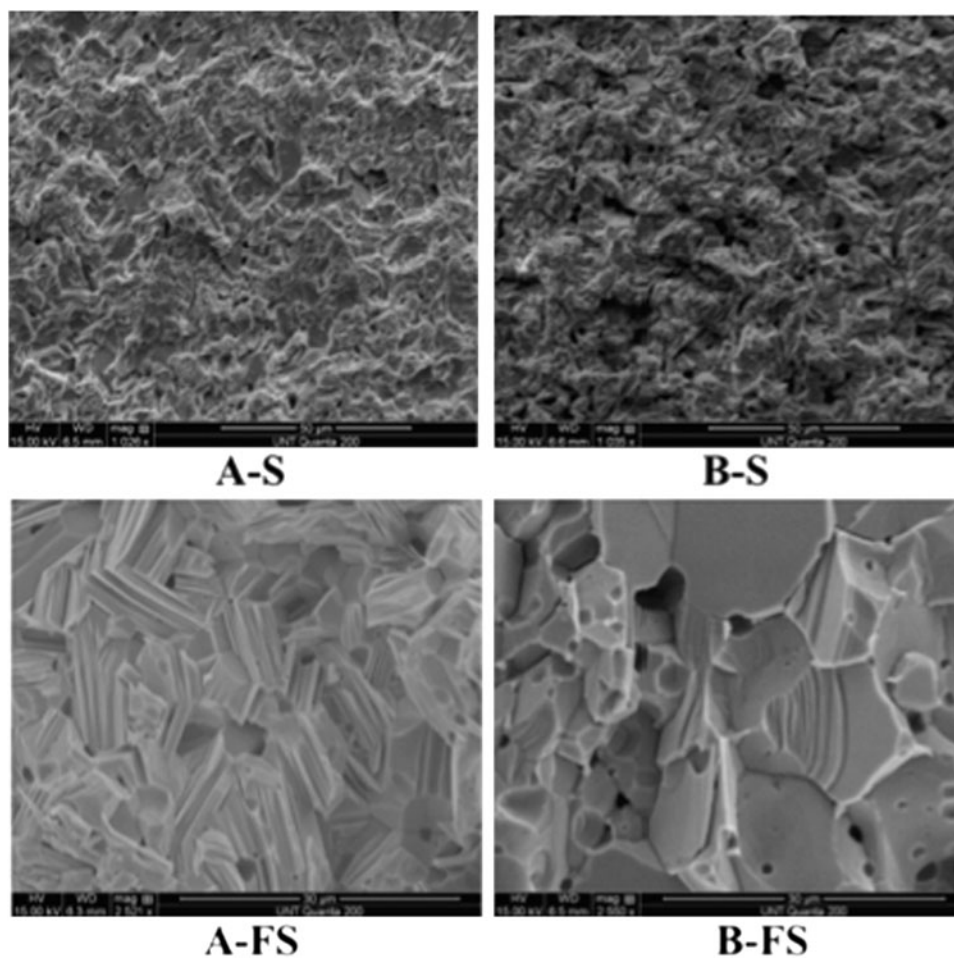


FIG. 3. ESEM micrographs of  $\text{Bi}_2\text{Te}_3$  surfaces (S) and fractured surfaces (FS) before (A-S, A-FS) and after TGA testing (B-S, B-FS).

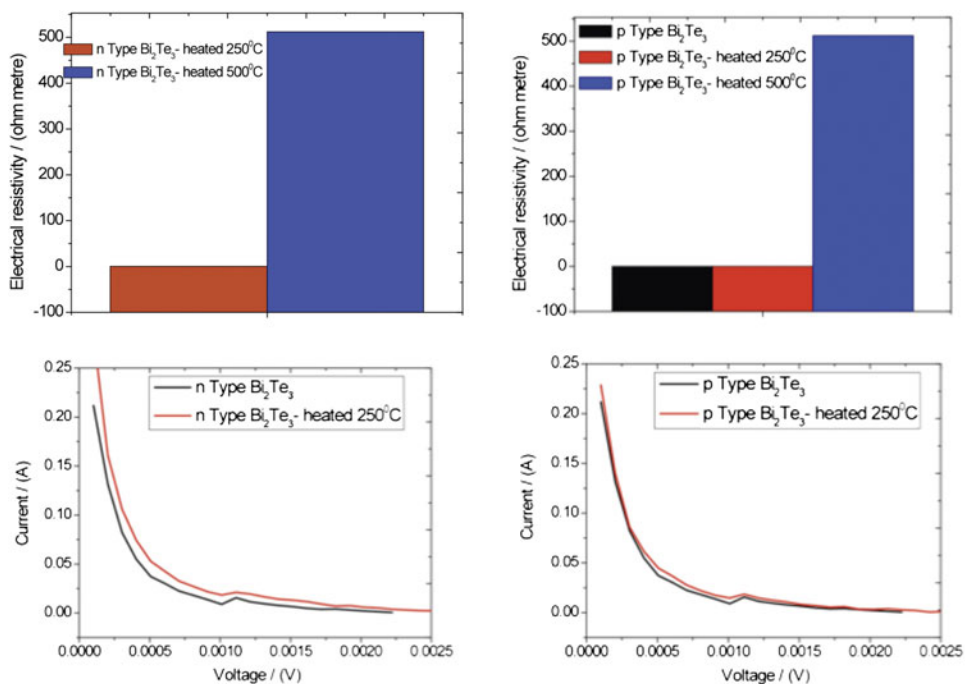


FIG. 4. Electrical resistivity of n-type and p-type  $\text{Bi}_2\text{Te}_3$  before and after heating at 250 and 500 °C.

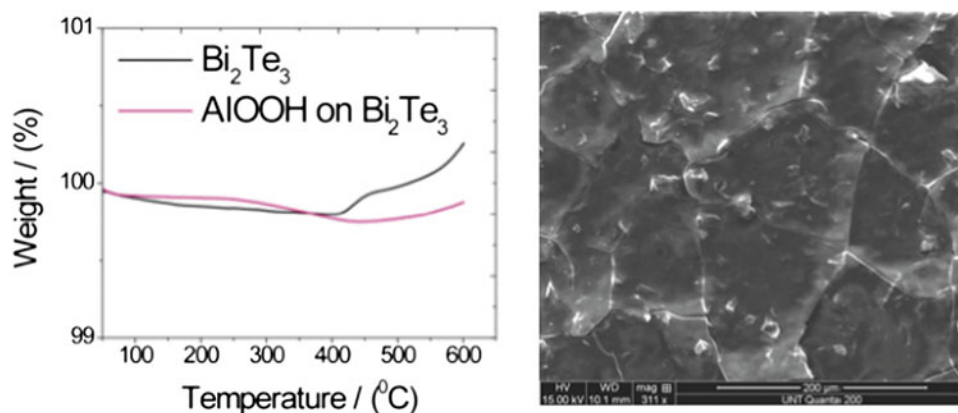


FIG. 5. Bi<sub>2</sub>Te<sub>3</sub> + AIOOH sample: (a) TGA and (b) ESEM.

insulate free spaces inside the TE devices and also to encapsulate both p-type and n-type TE materials. We thus expect to alleviate several problems listed above: moisture will not have easy access to interior of the device; structural integrity will be enhanced; corrosive agents will not have easy access; temperature cycling will not cause fast degradation, in particular sublimation will be eliminated; low thermal conductivity of the added materials will ensure concentration of heat flow through the TE device. The overall desired results will be TE systems operating at high temperatures with improved performance and longer lifetime.

An inorganic ceramic coating could accomplish the above objectives—as mentioned previously. Bi<sub>2</sub>Te<sub>3</sub> specimens were coated with boehmite via dip coating and dried at 250 °C for 12 h to provide smoother surfaces.

Figure 5 shows that Bi<sub>2</sub>Te<sub>3</sub> coated with boehmite displays better thermal stability all the way up to 600 °C than the bare Bi<sub>2</sub>Te<sub>3</sub>. Below 400 °C the coating prevents sublimation. However, above 350 °C we see a slight weight gain. ESEM analysis shows formation of cracks and it is likely that oxygen penetrates inside through the cracks and chemically reacts with Bi<sub>2</sub>Te<sub>3</sub> components. The main reason for cracking of the ceramic coating seems to be the coating thickness exceeding 1 μm. We have to apply fairly thick coatings because of relatively rough surface of the unencapsulated Bi<sub>2</sub>Te<sub>3</sub> substrate. The minimum roughness was ≈0.78 μm, the maximum ≈1.16 μm. The n-type material has higher roughness than the p-type.

Given the results obtained with a ceramic coating, we moved to polymeric coatings. Expected advantages of HTPs for encapsulation of TE materials are flexibility, easiness of processing and ability to tailor properties through chemical modification or fillers. However, pitfalls are also possible. We are dealing here with the coating very different from the substrate. As discussed by Kopczynska and Ehrenstein<sup>28</sup> and more in detail in a book by Desai and Kapral,<sup>29</sup> properties of multiphase composites are strongly controlled by interfaces. Even interfacial

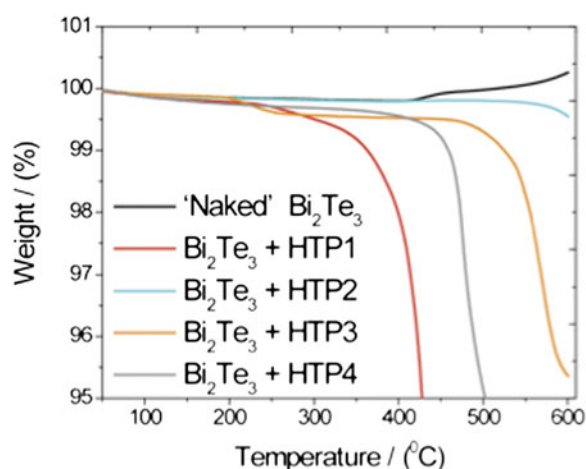


FIG. 6. TGA thermograms of “naked” and encapsulated Bi<sub>2</sub>Te<sub>3</sub>.

curvatures are important.<sup>29</sup> Diffusion of moisture, gases or liquids across ceramic surfaces can be neglected for most purposes while such diffusion is fairly typical for polymers<sup>30–32</sup> and usually causes swelling.<sup>33–35</sup> As before, we first used TGA for evaluation of four different HTP coatings; see Fig. 6.

Note the small scale in Fig. 5 starting at 95%. As demonstrated above, Bi<sub>2</sub>Te<sub>3</sub> loses weight in temperatures up to 400 °C and then begins to gain weight through oxidation around 400 °C. The encapsulated samples show good thermal stability and lack of oxidation.

Subsequently, Bi<sub>2</sub>Te<sub>3</sub> encapsulated with HTP2 was heated twice to 500 °C and each time left for 5 min at 500 °C. The respective TGA results are shown in Fig. 7; again note the scale, beginning here at 99.8%. In the second heating cycle there is hardly any change of weight; the volatiles were eliminated in the first cycle. Two cycles up to 500 °C have not caused thermal degradation, sublimation or oxidation of the TE material.

We find that encapsulating Bi<sub>2</sub>Te<sub>3</sub> TE material with HTPs provided proof of concept for the capability to

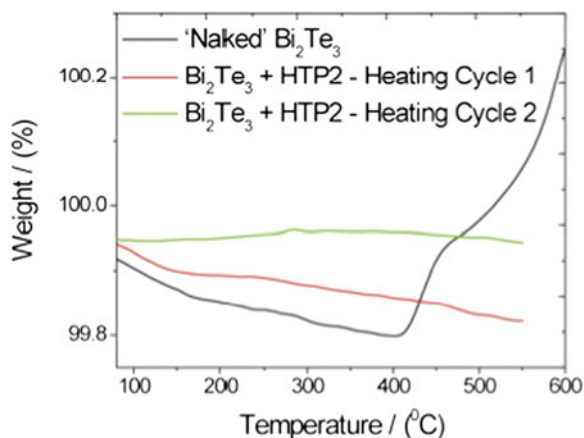


FIG. 7. TGA thermograms: “naked” and encapsulated  $\text{Bi}_2\text{Te}_3$  samples after two heating cycles.

extend the service life of TE devices at high temperatures up to 550 °C. This provides a solution for  $\text{Bi}_2\text{Te}_3$  TEGs with their relatively low operating temperature of 250 °C and it opens possibilities for applications with the higher temperature TE materials such as PbTe and skutterudite antimonides. We have used HTPs and their blends, but there are also other options including polymer irradiation<sup>36,37</sup> or using fillers.<sup>38–44</sup> The last option should enable adjustment of thermal expansivity.

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